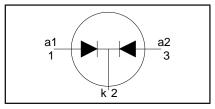
PBYR1545CT, PBYR1545CTB series

FEATURES

Low forward volt drop

- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 40 \text{ V}/45 \text{ V}$$

$$I_{O(AV)} = 15 \text{ A}$$

$$V_F \le 0.57 \text{ V}$$

GENERAL DESCRIPTION

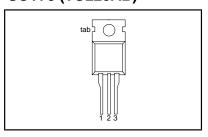
Dual, common cathode schottky rectifier diodes in a conventional leaded plastic package and a surface mounting plastic package. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR1545CT series is supplied in the SOT78 conventional leaded package. The PBYR1545CTB series is supplied in the SOT404 surface mounting package.

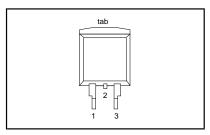
PINNING

PIN	DESCRIPTION	
1	anode 1 (a)	
2	cathode (k) 1	
3	anode 2 (a)	
tab	cathode (k)	

SOT78 (TO220AB)



SOT404



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS MIN. MAX.		X.	UNIT	
		PBYR15 PBYR15		40CT 40CTB	45CT 45CTB	
V_{RRM}	Peak repetitive reverse voltage		-	40	45	V
V_{RWM}	Working peak reverse voltage		-	40	45	V
V_R	Continuous reverse voltage	T _{mb} ≤ 107 °C	-	40	45	V
I _{O(AV)}	Average rectified forward current (both diodes conducting)	square wave; $\delta = 0.5$; $T_{mb} \le 128 ^{\circ}C$	-	15		A
I _{FRM}	Repetitive peak forward current (per diode)	square wave; $\delta = 0.5$; $T_{mb} \le 128 ^{\circ}\text{C}$	-	15	5	Α
I _{FSM}	Non-repetitive peak forward current per diode	t = 10 ms t = 8.3 ms sinusoidal; T _j = 125 °C prior to surge; with reapplied V _{PRM(max)}	-	13 15		A A
I _{RRM}	Peak repetitive reverse surge current per diode	pulse width and repetition rate limited by T _{i max}	-	1		Α
T _j	Operating junction temperature	Illiax	-	15	0	°C
T_{stg}	Storage temperature		- 65	17	5	°C

^{1.} It is not possible to make connection to pin 2 of the SOT404 package.

Rectifier	diodes
Schottky	barrie

PBYR1545CT, PBYR1545CTB series

THERMAL RESISTANCES

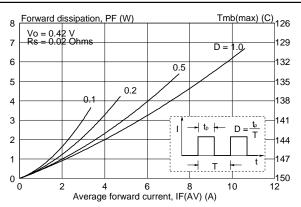
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th i-a}	to mounting base Thermal resistance junction	per diode both diodes SOT78 package in free air SOT404 package, pcb mounted, minimum	- - -	- - 60 50	3 2 -	K/W K/W K/W
	to ambient	footprint, FR4 board				10,77

ELECTRICAL CHARACTERISTICS

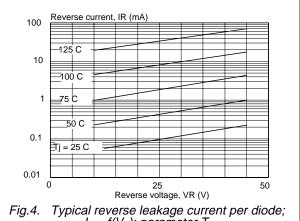
T_i = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{F}	Forward voltage per diode	I _F = 7.5 A; T _j = 125°C I _F = 15 A; T _i = 125°C	-	0.44	0.57	V
			-	0.63	0.72	V
		I _F = 15 A	-	0.62	0.84	l V
l _R	Reverse current per diode	$V_R = V_{RWM}$	-	0.22	1	mA
		$V_R = V_{RWM}$; $T_i = 100$ °C	-	18	25	mA
C _d	Junction capacitance per diode	$V_R = V_{RWM}; T_j = 100^{\circ}C$ $V_R = 5 V; f = 1 MHz, T_j = 25^{\circ}C \text{ to } 125^{\circ}C$	-	270	-	pF

PBYR1545CT, PBYR1545CTB series



Maximum forward dissipation $P_F = f(I_{F(AV)})$ per diode; square current waveform where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$.



 $I_R = f(V_R)$; parameter T_i

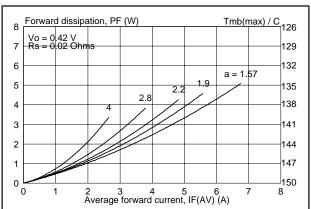


Fig.2. Maximum forward dissipation $P_F = f(I_{F(AV)})$ per diode; sinusoidal current waveform where a = form $factor = I_{F(RMS)} / I_{F(AV)}$.

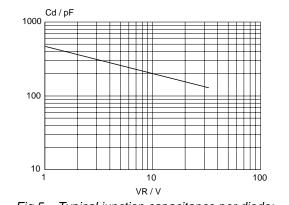


Fig.5. Typical junction capacitance per diode; $C_d = f(V_R)$; f = 1 MHz; $T_j = 25^{\circ}C$ to $125^{\circ}C$.

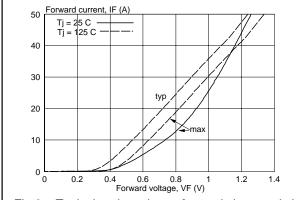
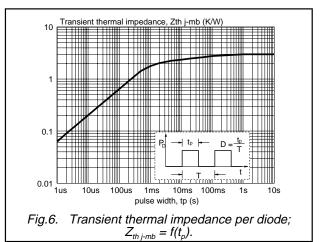
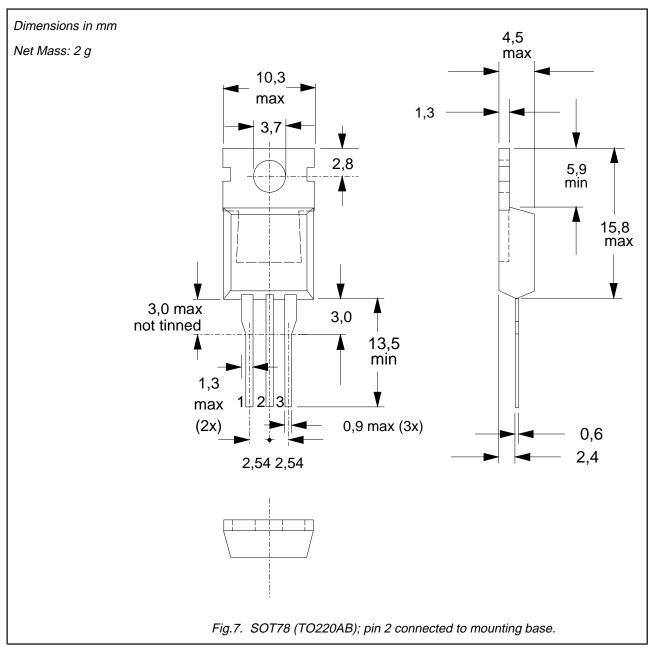


Fig.3. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_i



PBYR1545CT, PBYR1545CTB series

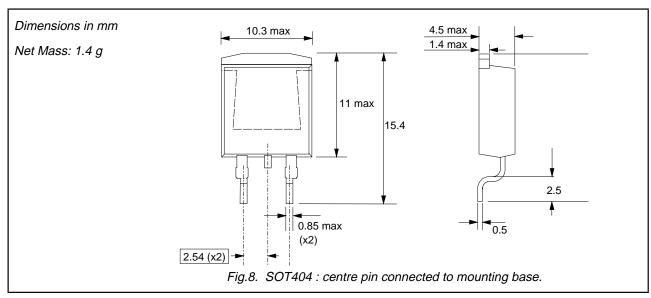
MECHANICAL DATA



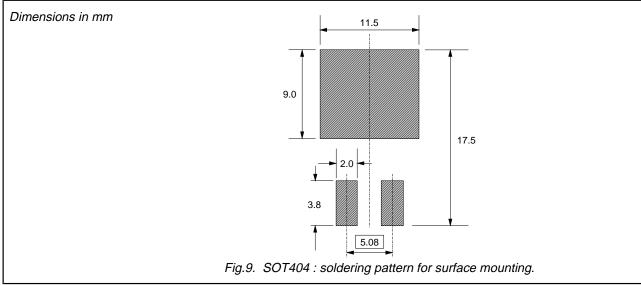
- Notes
 1. Refer to mounting instructions for SOT78 (TO220) envelopes.
 2. Epoxy meets UL94 V0 at 1/8".

PBYR1545CT, PBYR1545CTB series

MECHANICAL DATA



MOUNTING INSTRUCTIONS



Notes

1. Epoxy meets UL94 V0 at 1/8".

Rectifier	diodes
Schottky	barrier

PBYR1545CT, PBYR1545CTB series

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification This data sheet contains final product specifications.				
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Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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